



ESD Protection Diodes with Ultra-Low Capacitance

The ESD9 is designed to protect voltage sensitive components that require ultra-low capacitance from ESD and transient voltage events. Excellent clamping capability, low capacitance, low leakage, and fast response time, make these parts ideal for ESD protection on designs where board space is at a premium. Because of its low capacitance, it is suited for use in high frequency designs such as USB 2.0 high speed and antenna line applications.

Specification Features:

- Ultra Low Capacitance 0.6 pF
- · Low Clamping Voltage
- Small Body Outline Dimensions: 0.039" x 0.024" (1.00 mm x 0.60 mm)
- Low Body Height: 0.016" (0.4 mm)
- Stand-off Voltage: 5 V
- Low Leakage
- Response Time is Typically < 1.0 ns
- This is a Pb-Free Device

• IEC61000-4-2 Level 4 ESD Protection

Mechanical Characteristics:

CASE: Void-free, transfer-molded, thermosetting plastic

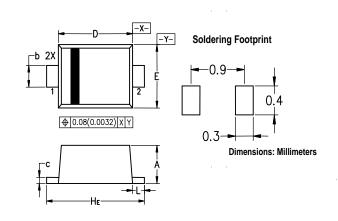
Epoxy Meets UL 94 V-0

LEAD FINISH: 100% Matte Sn (Tin)

QUALIFIED MAX REFLOW TEMPERATURE: 260°C

Device Meets MSL 1 Requirements

SOD-923



Dim		Millimeters		Inches			
	Min	Nom	Max	Min	Nom	Max	
Α	0.36	0.40	0.43	0.014	0.016	0.017	
b	0.15	0.20	0.25	0.006	0.008	0.010	
С	0.07	0.12	0.17	0.003	0.005	0.007	
D	0.75	0.80	0.85	0.030	0.031	0.033	
E	0.55	0.60	0.65	0.022	0.024	0.026	
HE	0.95	1.00	1.05	0.037	0.039	0.041	
L	0.05	0.10	0.15	0.002	0.004	0.006	

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
IEC 61000-4-2 (ESD) Contact Air		±20 ±20	kV
Total Power Dissipation on FR-5 Board (Note 1) @ T _A = 25°C	P_{D}	150	mW
Storage Temperature Range	T _{stg}	-55 to +150	°C
Junction Temperature Range	T_J	-55 to +125	°C
Lead Solder Temperature – Maximum (10 Second Duration)	TL	260	°C

SOD-923

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

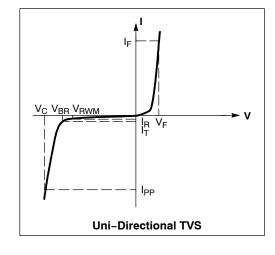
1. $FR-5 = 1.0 \times 0.75 \times 0.62$ in.

ESD9L5.0ST5G

ELECTRICAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

	<u>, </u>			
Symbol	Parameter			
I _{PP}	Maximum Reverse Peak Pulse Current			
V _C	Clamping Voltage @ I _{PP}			
V _{RWM}	Working Peak Reverse Voltage			
I _R	Maximum Reverse Leakage Current @ V _{RWM}			
V_{BR}	Breakdown Voltage @ I _T			
Ι _Τ	Test Current			
l _F	Forward Current			
V _F	Forward Voltage @ I _F			
P _{pk}	Peak Power Dissipation			
С	Capacitance @ V _R = 0 and f = 1.0 MHz			



^{*}See Application Note AND8308/D for detailed explanations of datasheet parameters.

ELECTRICAL CHARACTERISTICS ($T_A = 25$ °C unless otherwise noted, $V_F = 1.0$ V Max. @ $I_F = 10$ mA for all types)

		V _{RWM} (V)	I _R (μΑ) @ V _{RWM}	V _{BR} (V) @ I _T (Note 2)	ŀт	C (pF)	V _C (V) @ I _{PP} = 1 A (Note 3)	v _c
Device	Device Marking	Max	Max	Min	mA	Max	Max	Per IEC61000-4-2 (Note 4)
PESD9X5VUA	D	5.0	1.0	6.0	1.0	0.9	14	Figures 1 and 2 See Below

- 2. V_{BR} is measured with a pulse test current I_T at an ambient temperature of 25°C.
- Surge current waveform per Figure 5.
 For test procedure see Figures 3 and 4 and Application Note AND8307/D.

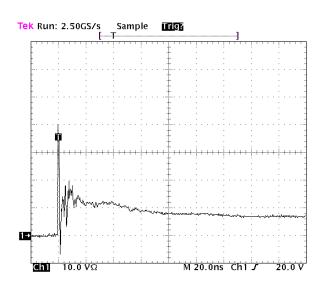


Figure 1. ESD Clamping Voltage Screenshot Positive 8 kV Contact per IEC61000-4-2

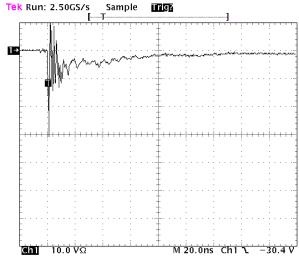
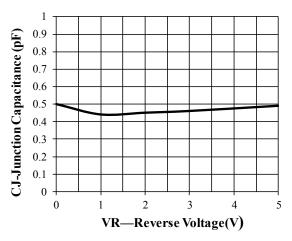
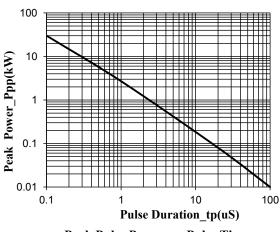


Figure 2. ESD Clamping Voltage Screenshot Negative 8 kV Contact per IEC61000-4-2

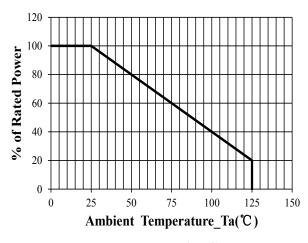
RATING AND VHARACTERISTIC CURVES(ESD9L5.0ST5G)



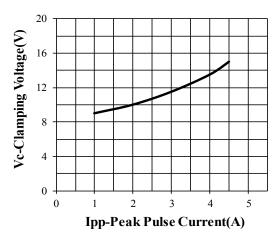
Junction Capacitance vs. Reverse Voltage



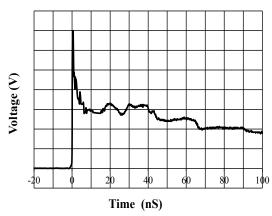
Peak Pulse Power vs. Pulse Time



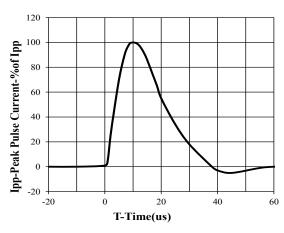
Power Derating Curve



Clamping Voltage vs. Peak Pulse Current



IEC61000-4-2 Pulse Waveform



8 X 20us Pulse Waveform